

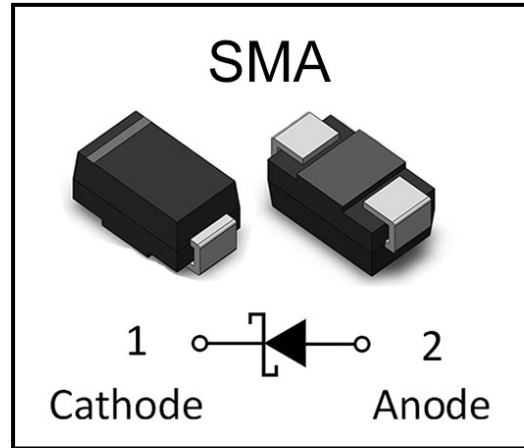
# SS52-SS520

Schottky Barrier Diode

## Features

- For surface mounted applications
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed:  
250°C/10 seconds at terminals

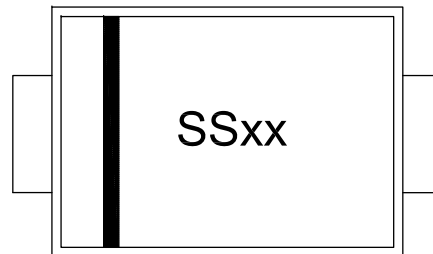
## Package



## Description

- Case: JEDEC DO-214AC molded plastic
- Terminals: Axial leads. Solderable per MIL-STD-750 Method 2026
- Polarity: Color band denotes cathode
- Mounting Position: Any

## Marking



## Ordering information

Part Number	SS52	SS53	SS54	SS55	SS56	SS58	SS510	SS515	SS520
Marking	SS52	SS53	SS54	SS55	SS56	SS58	SS510	SS515	SS520
Base qty	5K	5K	5K	5K	5K	5K	5K	5K	5K



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Maximum Ratings and Electrical Characteristics@T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameters	SS 52	SS 53	SS 54	SS 55	SS 56	SS 58	SS 510	SS 515	SS 520	Units	
V <sub>RRM</sub>	Maximum Repetitive Peak Reverse Voltage	20	30	40	50	60	80	100	150	200	V	
V <sub>RMS</sub>	Maximum RMS Reverse Voltage	14	21	28	35	42	56	70	105	140	V	
V <sub>DC</sub>	Maximum DC Blocking Voltage	20	30	40	50	60	80	100	150	200	V	
I <sub>(AV)</sub>	Maximum average forward Rectified Current	5.0									A	
I <sub>FSM</sub>	Non-repetitive peak forward surge current 8.3 ms singlehalf sine-wave	100									A	
V <sub>F</sub>	Maximum Forward Voltage at 5.0A DC	0.55		0.70		0.85		0.95			V	
I <sub>R</sub>	Maximum DC Reverse current T <sub>A</sub> =25°C at Rated DC Blocking Voltage T <sub>A</sub> =100°C	0.5					0.1					mA
		10					5					
C <sub>J</sub>	Typical Junction Capacitance	250									pF	
T <sub>J</sub>	Operating Temperature Range	-55 to +150									°C	
T <sub>STG</sub>	Storage Temperature Range	-55 to +150										
R <sub>θJA</sub>	Thermal Resistance <sup>(1)</sup>	60									°C/W	
R <sub>θJL</sub>		22										

Note:(1)Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B.with 0.2" x 0.2" (5.0 mm x 5.0 mm)copper pad areas.



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Typical Performance Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise noted)

Figure 1:  $I_O$ - $T_L$  Curve

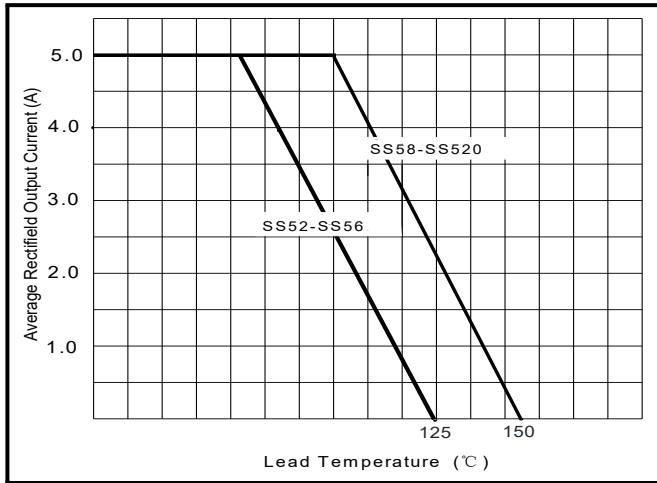


Figure 2: Surge Forward Current Capability

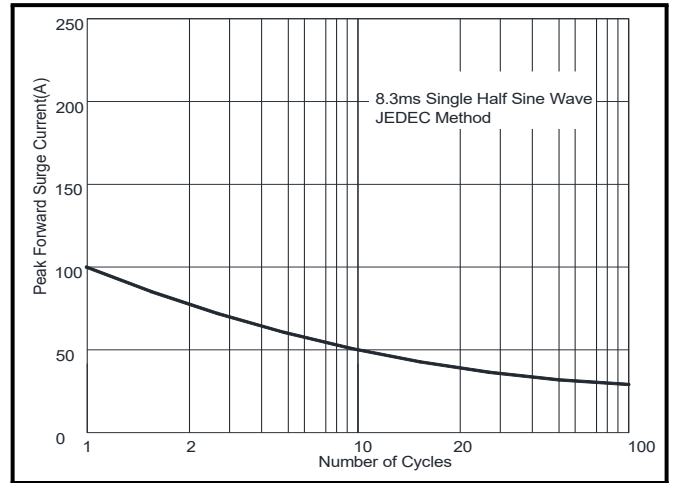


Figure 3: Typical Forward Characteristics

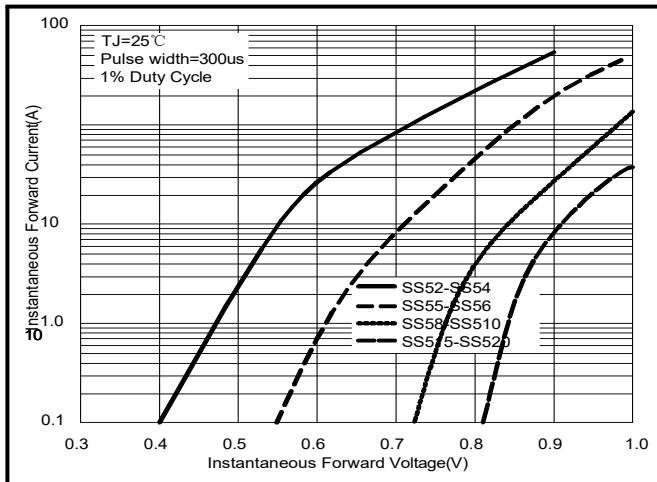
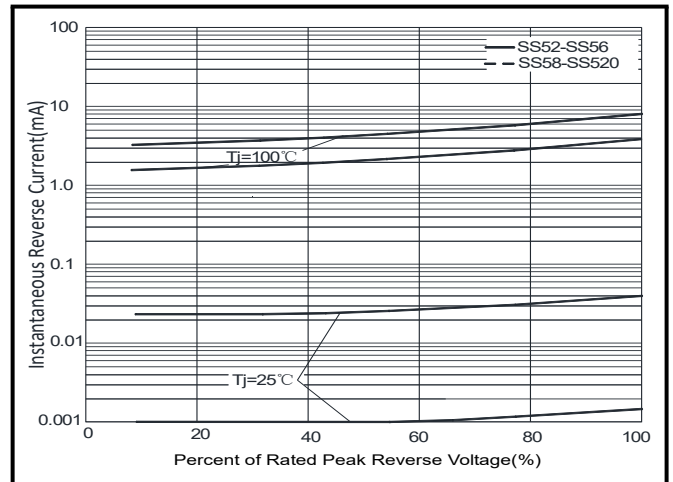


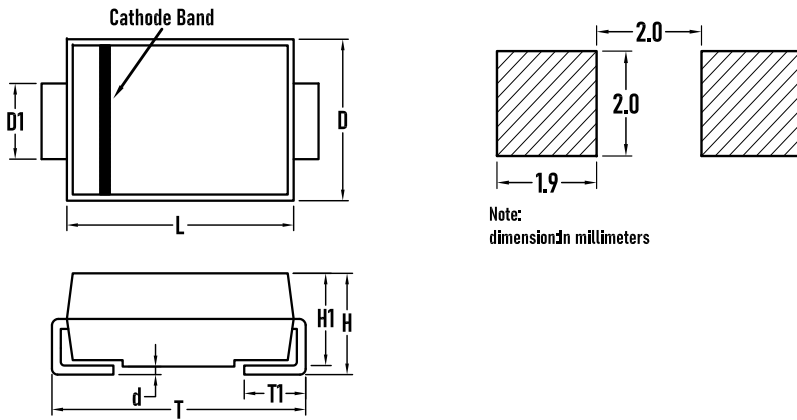
Figure 4: Typical Reverse Characteristics



# SS52-SS520

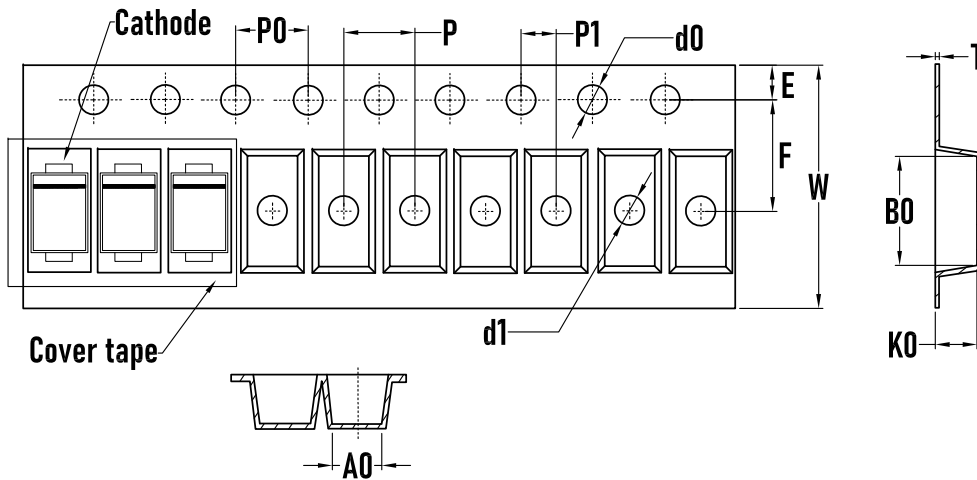
Schottky Barrier Diode

## Outline Drawing - SMA



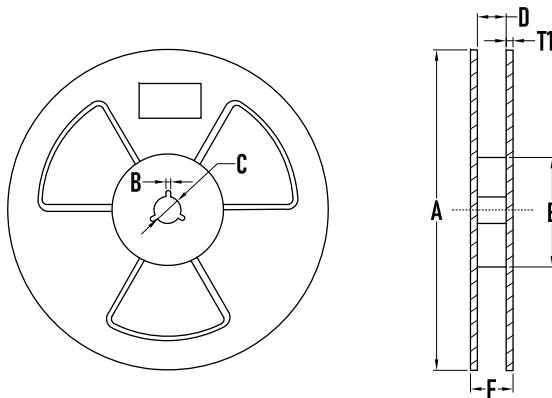
SYMBOL	MILLIMETER		Inches	
	MIN.	MAX.	MIN.	MAX.
D	2.5	2.9	0.098	0.114
D1	1.2	1.8	0.047	0.071
T	4.8	5.3	0.189	0.209
T1	0.8	1.5	0.031	0.059
d	—	0.2	—	0.008
H1	1.8	2.2	0.071	0.087
H	1.9	2.5	0.075	0.098
L	3.9	4.6	0.154	0.181

## Packaging Tape - SMA



SYMBOL	MILLIMETER
A0	2.70
B0	5.10±0.1
d0	1.50±0.1
d1	1.50±0.1
E	1.75±0.1
F	5.50±0.1
K0	2.40±0.1
P	4.00±0.1
P0	4.00±0.1
P1	2.00±0.1
W	12.00±0.1
T	0.2±0.02

## Packaging Reel



SYMBOL	MILLIMETER
A	323±2
B	3.0±0.2
C	15.0±0.5
D	13±2
E	73±2
T1	2.2±0.2
Quantity	5000PCS

